

5406 / 7406 Hex Inverter Buffer/Driver with Open-Collector High-Voltage Output

	Schottky TTL				High-Speed TTL				Low-Power Schottky TTL				Standard TTL				Low-Power TTL				
	Device Type		Package		Device Type		Package		Device Type		Package		Device Type		Package		Device Type		Package		
	C	P	M	CF	C	P	M	CF	C	P	M	CF	C	P	M	CF	C	P	M	CF	
T. I.													SN5406	J			W				
FAIRCHILD													SN7406	J			N				
MOTOROLA													FMS406/FM9N06	D			F				
N. S. C.													FC7406/FC9N06	D			P				
PHILIPS													SN7406				P				
SIGNETICS													DM5406	J			N				W
SIEMENS													DM7406	J			N				
FUJITSU													N7406								
HITACHI													SS406	F			A				W
MITSUBISHI													N7406	F			A				
NEC													FLH481								
TOSHIBA													TD7406				P				

Electrical Characteristics SN7406/SN5406
absolute maximum ratings over operating free-air temperature range

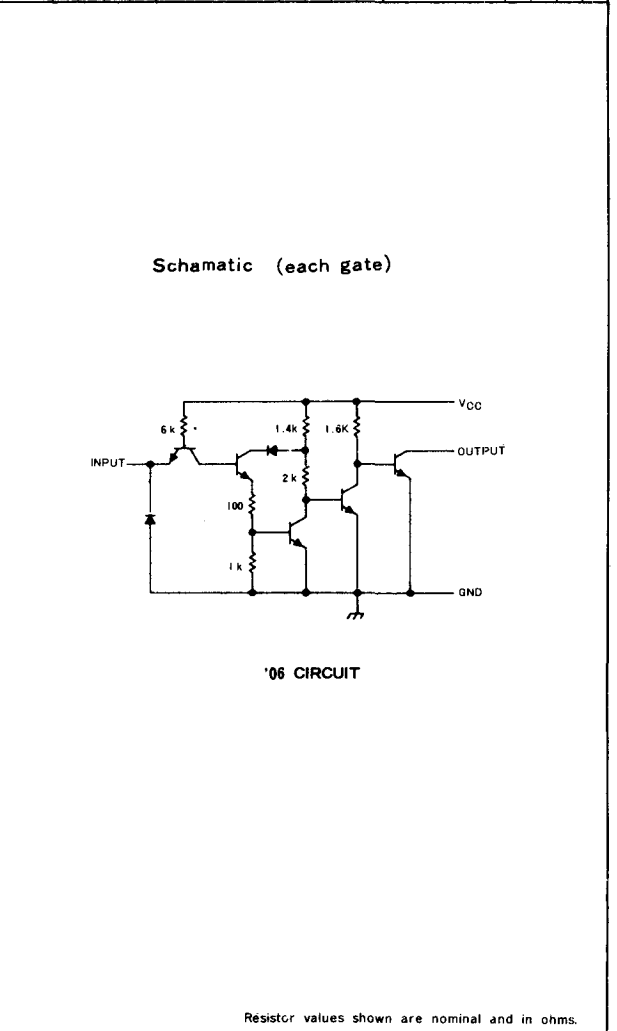
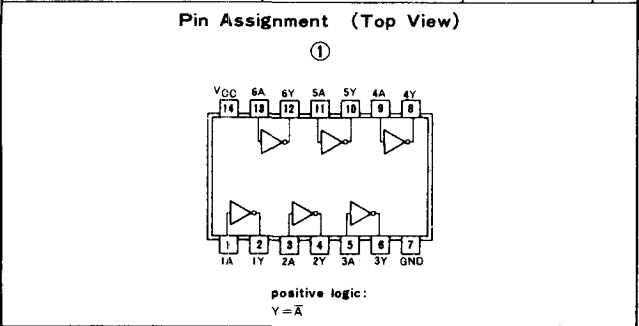
Supply voltage, V _{CC}	7V	Operating free air temperature range	SN54*	-55°C to 125°C
Input voltage	5.5V	Storage temperature range	SN74*	0°C to 70°C
Off-state (high-level) voltage applied to open-collector outputs	30V			-65°C to 150°C

recommended operating conditions

	SN5406			SN7406			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level output voltage, V _{OH}			30			30	V
Low-level output current, I _{OL}			30			40	mA
Operating free-air temperature, T _A	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range

PARAMETER	TEST CONDITIONS †	MIN	TYP ‡	MAX	UNIT	
V _{IH}	High-level input voltage		2		V	
V _{IL}	Low-level input voltage			0.8	V	
V _I	Input clamp voltage	V _{CC} =MIN, I _I =-12mA		-1.5	V	
I _{OH}	High-level output current	V _{CC} =MIN, V _{IL} =V _{IL} max, V _{OH} =MAX		250	µA	
V _{OL}	Low-level output voltage	V _{CC} =MIN, V _{IH} =2V, I _{OL} =16mA		0.4	V	
		V _{CC} =MIN, V _{IH} =2V, I _{OL} =MAX		0.7	V	
I _I	Input current at maximum input voltage	V _{CC} =MAX, V _I =5.5V		1	mA	
I _{IH}	High-level input current	V _{CC} =MAX, V _{IH} =2.4V		40	µA	
I _{IL}	Low-level input current	V _{CC} =MAX, V _{IL} =0.4V		-1.6	mA	
I _{CC}	Supply current	V _{CC} =MAX	Total, outputs high	30	48	mA
I _{CC}	Supply current	V _{CC} =MAX	Total, outputs low	32	51	mA
I _{CC}	Supply current	V _{CC} =5V	Average per gate (50% duty cycle)	5.17		mA
t _{PLH}	Propagation delay time, low-to-high-level output	V _{CC} =5V, T _A =25°C		10	15	ns
t _{PHL}	Propagation delay time, high-to-low-level output	C _L =15pF, R _L =110Ω		15	23	ns



† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ All typical values are at V_{CC}=5V, T_A=25°C.